

# BC807-25-7 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number BC807-25-7-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number BC807-25-7

Description TRANS PNP 45V 0.5A SOT23-3

Detailed Description Bipolar (BJT) Transistor PNP 45 V 500 mA 100MHz 3

10 mW Surface Mount SOT-23-3



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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
BC807-25-7	Diodes Incorporated
Series:	Product Status:
	Discontinued at Digi-Key
Transistor Type:	Current - Collector (Ic) (Max):
PNP	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA	160 @ 100mA, 1V
Power - Max:	Frequency - Transition:
310 mW	100MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3
Base Product Number:	
BC807	

## **Environmental & Export classification**

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





#### 45V PNP SMALL SIGNAL TRANSISTOR IN SOT23

#### **Features**

- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (BC817)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

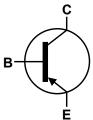
#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (approximate)

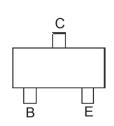




Top View



Device Symbol



Top View Pin-Out

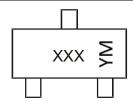
## **Ordering Information** (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC807-16-7-F	Standard	K5A	7	8	3,000
BC807-25-7-F	Standard	K5B	7	8	3,000
BC807-40-7-F	Standard	K5C	7	8	3,000
BC807-40-13-F	Standard	K5C	13	8	10,000

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



XXX = Product Type Marking Code (See table above)
YM = Date Code Marking
Y or Y = Year ex: I = 2021
M = Month ex: 9 = September

#### Date Code Key

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code		J	K	L	М	N	0	Р	R	S	T	U
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
WOILLI	Jan	1 65	IVIGI	Λþi	iviay	oun	Jui	,9	ООР			200
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-50	V
Collector-Emitter Voltage	$V_{CEO}$	-45	V
Emitter-Base Voltage	$V_{EBO}$	-5.0	V
Continuous Collector Current	Ic	-0.5	Α
Peak Collector Current	I <sub>CM</sub>	-1.0	Α
Peak Base Current	I <sub>BM</sub>	-200	mA

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	Б	310	mW	
Power Dissipation	(Note 6)	$P_{D}$	350	IIIVV	
Thermal Desistance, Junction to Ambient	(Note 5)	Б	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	357	C/VV	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range	_	$T_{J,}T_{STG}$	-55 to +150	°C	

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

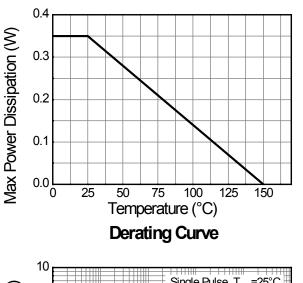
#### Notes:

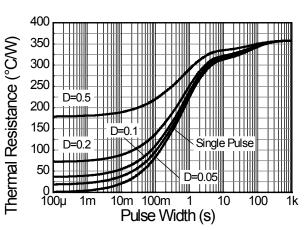
- 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; device measured when operating in steady state condition.

  6. Same as Note 5, except the device is mounted on 15mm X 15mm FR4 PCB.
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

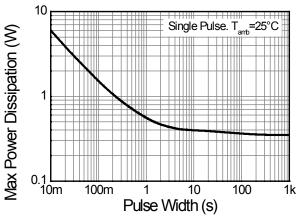


## **Thermal Characteristics and Derating Information**





**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

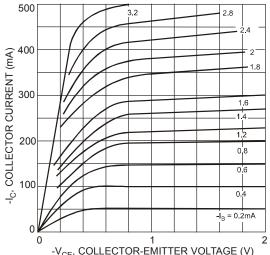
Characteristic			Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	-45	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	-5	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Cutoff Current		I <sub>CES</sub>	_	_	-100 -5.0	nΑ μΑ	V <sub>CE</sub> = -45V V <sub>CE</sub> = -25V, T <sub>J</sub> = +150°C
Emitter-Base Cutoff Current		I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5.0V
DC Current Gain (Note 9)	BC807-16 BC807-25 BC807-40	h <sub>FE</sub>	100 160 250		250 400 600		V <sub>CE</sub> = -1.0V, I <sub>C</sub> = -100mA
De Current Gain (Note 9)	BC807-16 BC807-25 BC807-40		60 100 170	_	_	_	V <sub>CE</sub> = -1.0V, I <sub>C</sub> = -300mA
Collector-Emitter Saturation Voltage (Note 9)		V <sub>CE(sat)</sub>	_	_	-0.7	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Voltage (Note 9)		V <sub>BE(on)</sub>	_	_	-1.2	V	V <sub>CE</sub> = -1.0V, I <sub>C</sub> = -300mA
Gain Bandwidth Product		f⊤	100	_	_	MHz	V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -10mA, f = 50MHz
Collector-Base Capacitance		C <sub>CBO</sub>	_	_	12	pF	V <sub>CB</sub> = -10V, f = 1.0MHz

Note:

9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%



## Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



-V<sub>CE</sub>, COLLECTOR-EMITTER VOLTAGE (V)
Figure 1 Typical Collector Current vs. Collector-Emitter Voltage

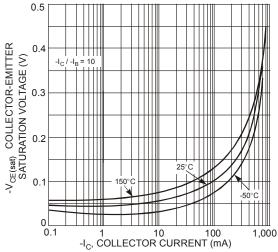


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

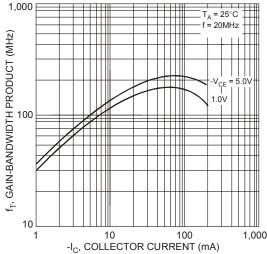


Figure 5 Typical Gain-Bandwidth Product vs. Collector Current

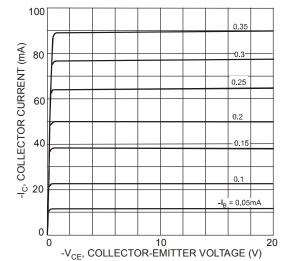


Figure 2 Typical Collector Current vs. Collector-Emitter Voltage

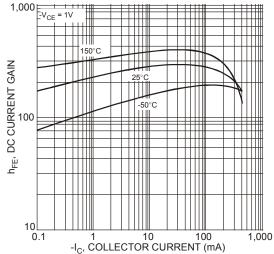


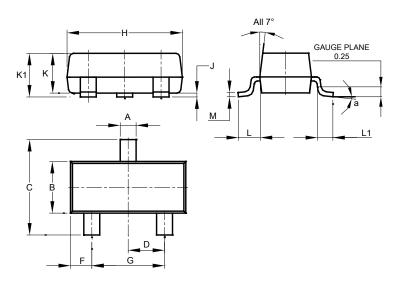
Figure 4 Typical DC Current Gain vs. Collector Current



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

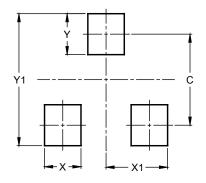


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.0



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